

## **Vishay Siliconix**

## Dual N-Channel 150-V (D-S) MOSFET

### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

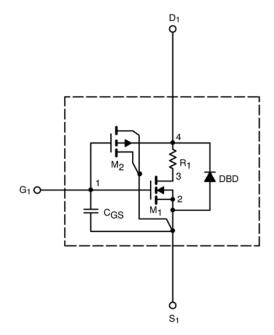
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

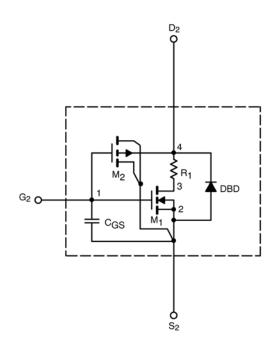
#### DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to  $125^{\circ}$ C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

# A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### SUBCIRCUIT MODEL SCHEMATIC





This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.



SPECIFICATIONS (T <sub>J</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A	2.3		V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{\text{DS}} \geq 5$ V, $V_{\text{GS}}$ = 10 V	53		А
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	$V_{GS}$ = 10 V, I <sub>D</sub> = 4.1 A	0.088	0.088	Ω
		$V_{GS}$ = 6 V, I <sub>D</sub> = 3.9 A	0.101	0.096	
Forward Transconductance <sup>a</sup>	<b>g</b> <sub>fs</sub>	$V_{DS}$ = 15 V, $I_{D}$ = 4.1 A	7	10	S
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{\rm S}$ = 2.9 A, $V_{\rm GS}$ = 0 V	0.76	0.77	V
Dynamic <sup>b</sup>					
Total Gate Charge	Qg	$V_{DS}$ = 75 V, $V_{GS}$ = 10 V, $I_{D}$ = 4.1 A	16.4	17	nC
Gate-Source Charge	Q <sub>gs</sub>		3.9	3.9	
Gate-Drain Charge	Q <sub>gd</sub>		5.5	5.5	
Turn-On Delay Time	t <sub>d(on)</sub>	$\label{eq:V_DD} \begin{array}{l} \textbf{V}_{\text{DD}} = \textbf{75} \ \textbf{V}, \ \textbf{R}_{\text{L}} = \textbf{75} \ \Omega \\ \textbf{I}_{\text{D}} \cong \textbf{1} \ \textbf{A}, \ \textbf{V}_{\text{GEN}} = \textbf{10} \ \textbf{V}, \ \textbf{R}_{\text{G}} = \textbf{6} \ \Omega \end{array}$	7	14	ns
Rise Time	tr		18	13	
Turn-Off Delay Time	t <sub>d(off)</sub>		24	36	
Fall Time	t <sub>f</sub>		16	18	

Notes a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2%. b. Guaranteed by design, not subject to production testing.



## **SPICE Device Model Si7956DP**

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T<sub>C</sub> = –55°C

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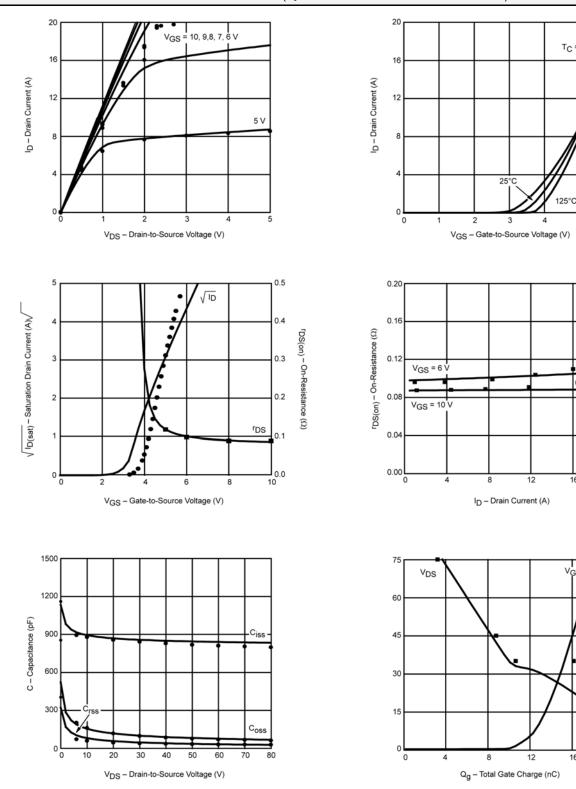
16

VGS

16

6

COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)



Note: Dots and squares represent measured data.



Vishay

# Disclaimer

All product specifications and data are subject to change without notice.

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